

BSC520N15NS3GATMA1

Data Sheet

N-Channel MOSFET, 21 A, 150 V OptiMOS 3, 8-Pin TDSON Infineon

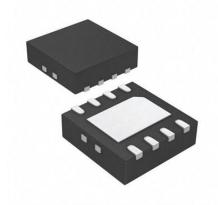
Manufacturers <u>Infineon Technologies Corporation</u>

Package/Case PG-TDSON-8

Product Type Transistors

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for BSC520N15NS3GATMA1 or <u>Emailto:scales@ovaga.com</u> We will contact you in 12 hours.

RFO

General Description

The 150V OptiMOSTM achieves a reduction in R $_{DS(on)}$ of 40% and of 45% in figure of merit (FOM) compared to the next best competitor. This drastic improvement opens new possibilities like moving from leaded packages to SMD packages or effectively replacing two old parts with one OptiMOSTM part.

Features

Excellent switching performance

World's lowest R DS(on)

Very low Q g and Q gd

Excellent gate charge x R DS(on) product (FOM)

RoHS compliant-halogen free

MSL1 rated 2

Environmentally friendly

Increased efficiency

Highest power density

Less paralleling required

Smallest board-space consumption

Easy-to-design products

Application

Synchronous rectification for AC-DC SMPS

Isolated DC-DC converters (telecom and datacom systems)

Or-ing switches and circuit breakers in 48V systems

Class D audio amplifiers

Related Products



BSP613P

Infineon Technologies Corporation SOT-223



BSB013NE2LXI

Infineon Technologies Corporation WDSON-2



BSC030N08NS5ATMA1

Infineon Technologies Corporation TDSON-8



BSC016N06NSATMA1

Infineon Technologies Corporation DSON-8



BSC011N03LS

Infineon Technologies Corporation PG-TDSON-8



BSC014N04LSATMA1

Infineon Technologies Corporation tdson-8



BSC026N08NS5ATMA1

Infineon Technologies Corporation TDSON-8



BSC066N06NSATMA1

Infineon Technologies Corporation TDSON-8